## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re <b>Divisional</b> Application of:	)
Mitsuru SEKIGUCHI	) Art Unit Group: 2813
Based on US Serial No. 09/931,190	) Examiner: Duy Vu Nguyen Deo
Which Was Filed: August 17, 2001	) Confirmation No.: 1378
For: SEMICONDUCTOR DEVICE AND	)
MANUFACTURING METHOD OF THE SAME	) Date: June 23, 2003

## INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA. 22313-1450 Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicants hereby submit the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98. Pursuant to 37 C.F.R. § 1.98. All the references cited on the PTO-1449 From were filed in the parent application Serial No.: 09/931,190 filed August 17, 2001.

It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initialed copy of this form be returned to the undersigned.

The Commissioner is hereby authorized to charge any fees connected with this filing which may be required now, or credit any overpayment to Deposit Account No. 19-2380.

Respectfully submitted,

Donald R. Studebaker

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Substitute	e for form l	449A/PTO					Co	mplete	if Known	,			
INFORMATION DISCLOSURE			Application Number				Not Yet Assigned						
INFORMATION DISCLOSURE			Filing Date	June 23, 2003									
STATEMENT BY APPLICANT			First Named Inventor				Mitsuru SEKIGUCHI						
(use as many sheets as necessary)			Art Unit				2813						
					Examiner Name				Not Yet Assigned				
Sheet	1	of	1		Attorney Docket Nu		740819-1014						
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Examiner	Cite	Cite U.S. Patent Document					Name of Patentee or Applicant of Cited Document						
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	Country Code <sup>3</sup> Number <sup>4</sup> (if known)					Document Document		Figures Appear		1			
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	1995, with English Translation												
Examiner Signature				Date Consid	ered								

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kinds Codes of USPTO Patent Documents at <a href="https://www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

<sup>&</sup>lt;sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> Applicant is to place a check mark here if English language Translation is attached.